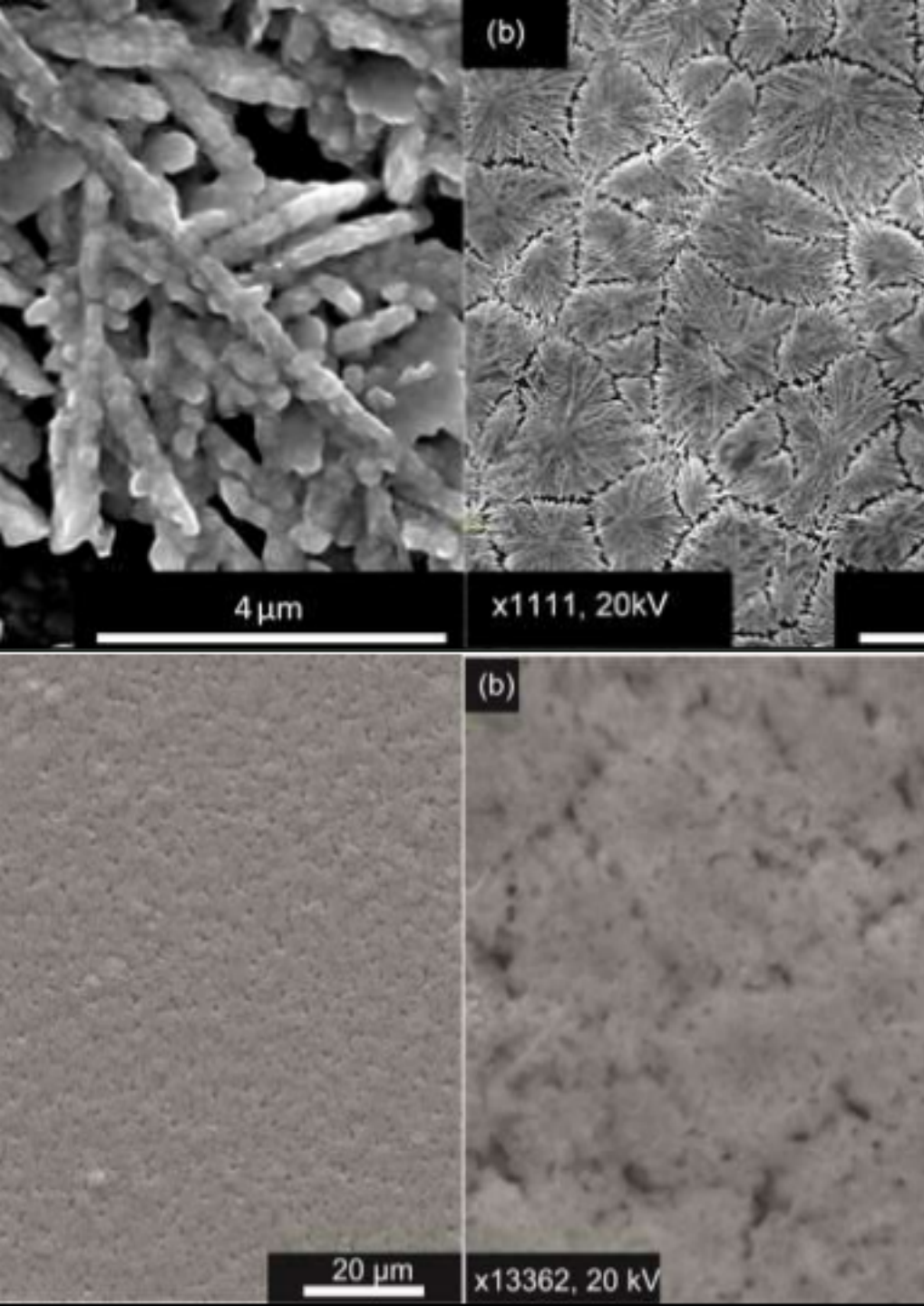


# Optimizing Lattice Energy in Irregular CM

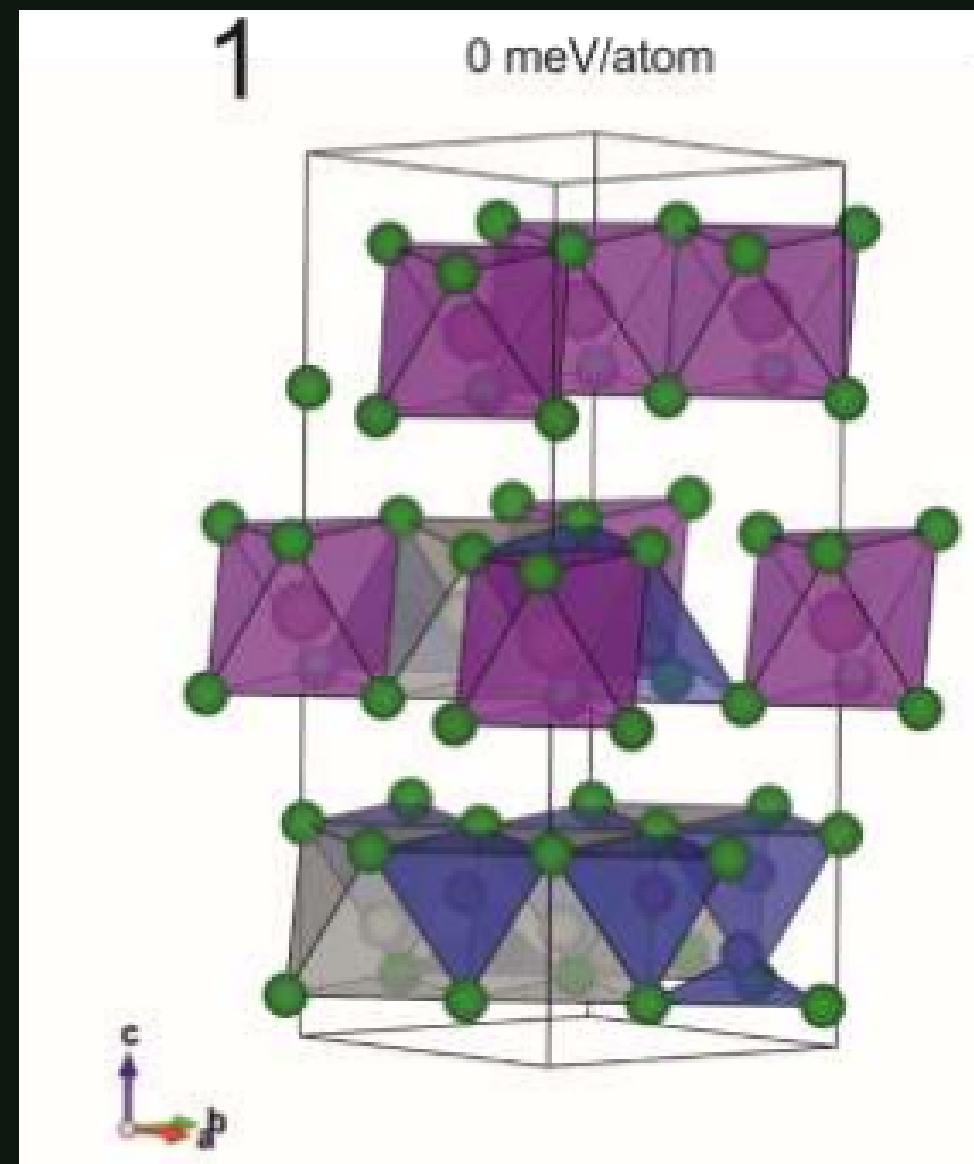
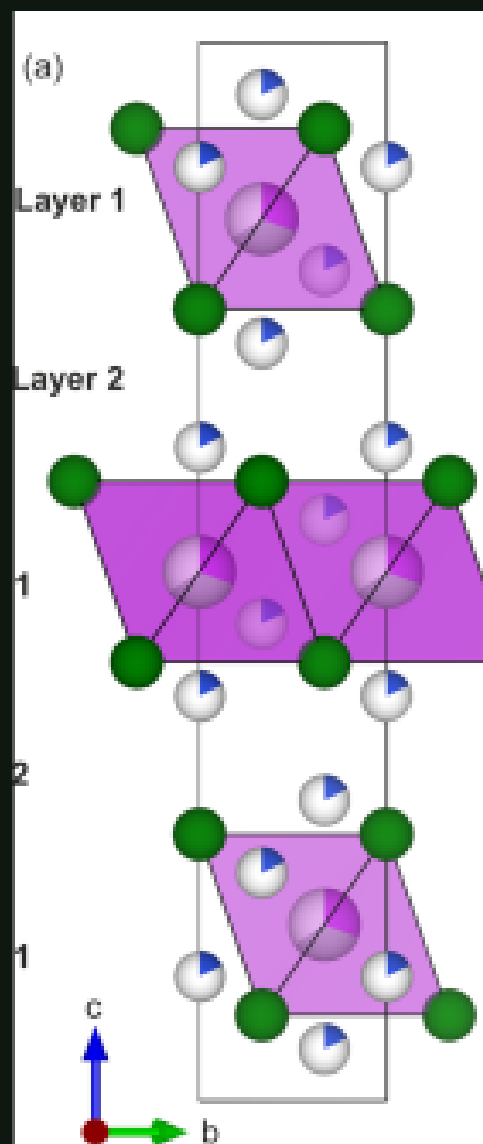
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**UToledo REU 2023**



## Background

- New lead-free semiconductor  $\text{Cu}_2\text{AgBiI}_6$  synthesized at University of Liverpool has promising applications in photovoltaics
- Initial research focused on experimental properties, simulations of internal structure were unoptimized and worth further investigation
- Worth researching: if we're going to put this into a solar panel, we should know its structure!



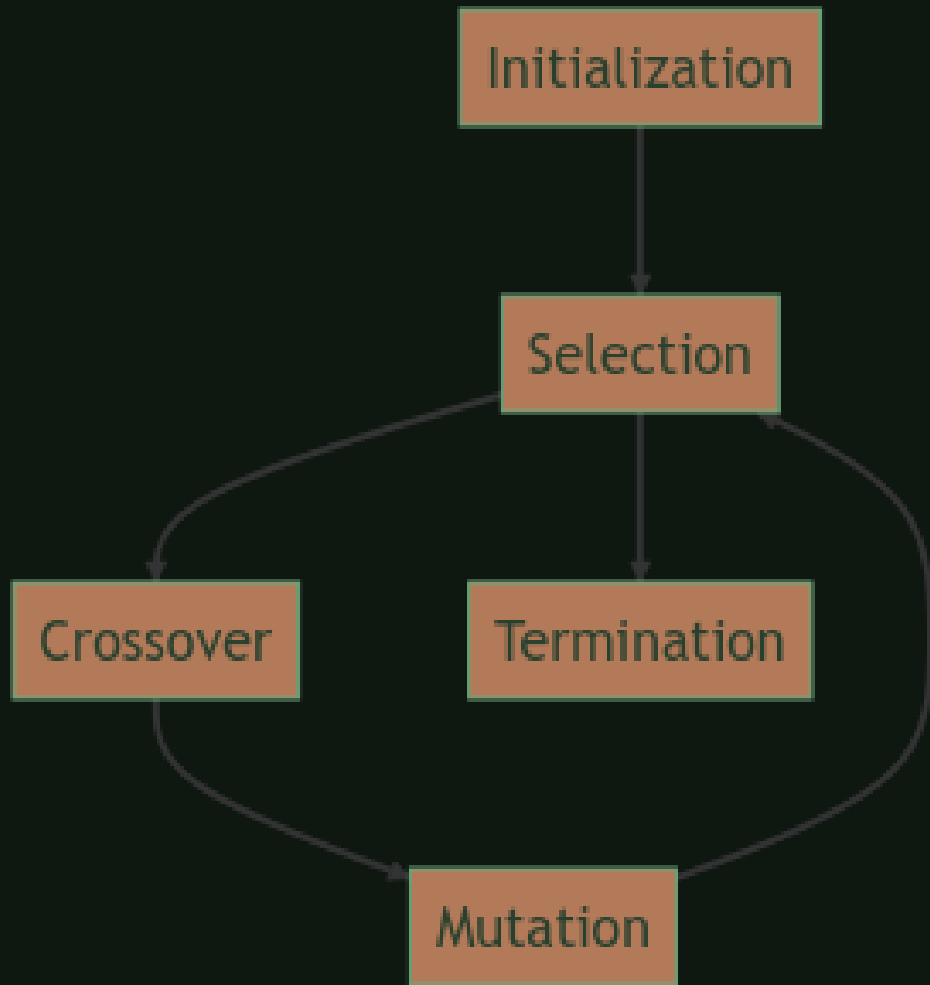
## The problem

How can we efficiently find the global minimum of a discrete function with unpredictable behavior and a very large finite domain?

$$\binom{108}{18} \text{Cu} * \left[ \binom{27}{9} * \binom{18}{9} \right] \text{Ag/Bi} = 3.173 * 10^{31} \text{ configurations}$$

## Big number

- TB =  $10^{12}$  bytes, would need 4 quintillion 1 TB storage drives to represent each configuration with 1 bit
- In microns, roughly the diameter of the observable universe 🪐🌌



## My approach

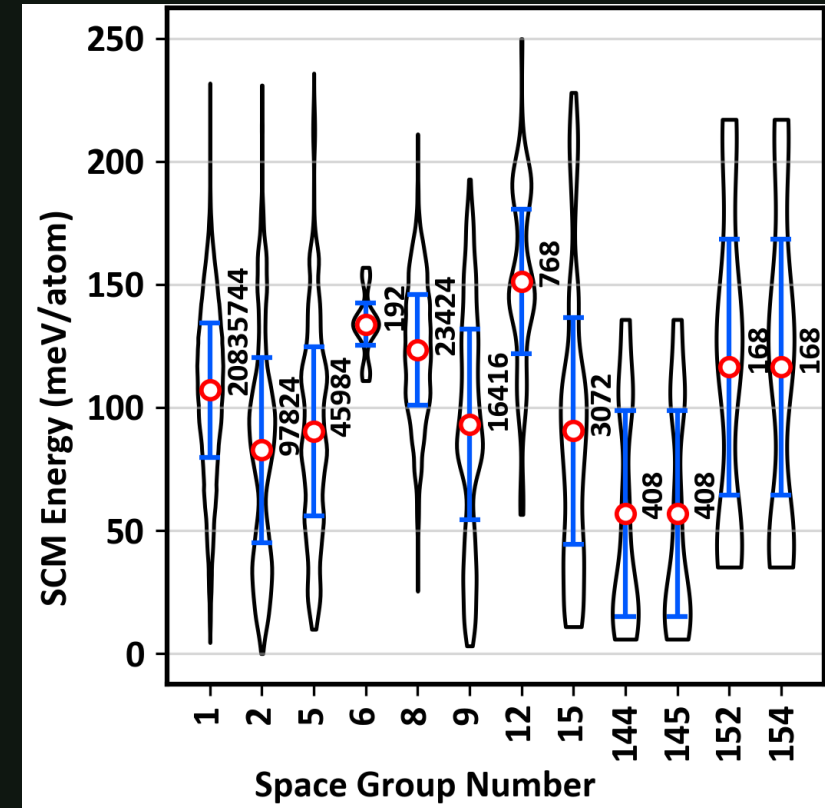
- Genetic algorithm converges on minimum while only looking at a small sample of the possible configurations
- Easily parallelizable, can run as many simulations as CPU threads available at once
- Use in this field is an active research area, especially with irregular materials

# Thank you!

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# First generation

- Some correlation between crystal symmetry/regularity and lattice energy in similar materials, many exceptions
- Skewing the first generation of configurations towards highly symmetric (high space group) configurations could lead to a faster convergence on a minimum.
- Accomplish this by binning the randomly generated first generation
  - Each bin is equal size but
  - Number of space groups represented in each bin varies



# Generating child configurations

- Configs for future generations are generated from the best of the previous generation
- Crossover: site filling is determined by indexing the occupied sites of the parents and selecting at random
- Mutation: A few occupied atomic sites in the child configuration will be swapped with ones chosen at random, most often resulting in an atom switching with a vacancy.

